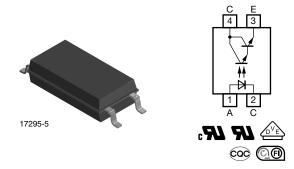


www.vishay.com

Vishay Semiconductors

Optocoupler, Photodarlington Output, SOP-4L, Long Mini-Flat Package



LINKS TO ADDITIONAL RESOURCES









DESCRIPTION

The TCLD1000 consists of a darlington phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4-lead SO6L package.

AGENCY APPROVALS

- UL
- cUL
- DIN EN 60747-5-2 (VDE 0884)

ORDERING INFORMATION

AGENCY CERTIFIED / PACKAGE

С

L

D

PART NUMBER

- BSI
- FIMKO
- CQC GB4943.1
- CQC GB8898

Т

UL, cUL, VDE, BSI

SOP-4L, mini-flat, long

FEATURES

- Extra low coupling capacity typical 0.2 pF
- High common mode rejection
- · Creepage current resistance according to VDE 0303 / IEC 60112 comparative tracking index: CTI ≥ 175



- Tested acc. 60950: AM4: 1997 clause 2.9.6.
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

0

0

CTR (%)

> 600

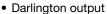
TCLD1000

- Switch-mode power supplies
- · Line receiver
- Computer peripheral interface
- Microprocessor system interface
- · Reinforced isolation provides circuit protection against electrical shock (safety class II)
- · Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):
 - for appl. class I to IV at mains voltage ≤ 300 V
- for appl. class I to III at mains voltage ≤ 600 V according to DIN EN 60747-5-2 (VDE 0884)

SOP-4L

10.2 mm









RoHS COMPLIANT HALOGEN FREE

GREEN (5-2008)

Rev. 2.1, 13-Feb-2023 Document Number: 83516

0

1



Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V _R	6	V			
Forward current		I _F	60	mA			
Forward surge current	t _p ≤ 10 μs	I _{FSM}	1.5	Α			
Power dissipation		P _{diss}	100	mW			
Junction temperature		Tj	125	°C			
OUTPUT							
Collector emitter voltage		V _{CEO}	35	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		I _C	80	mA			
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA			
Power dissipation		P _{diss}	150	mW			
Junction temperature		Tj	125	°C			
COUPLER							
Isolation test voltage (RMS)		V _{ISO}	5000	V_{RMS}			
Total power dissipation		P _{tot}	250	mW			
Operating ambient temperature range		T _{amb}	-55 to +100	°C			
Storage temperature range		T _{stg}	-55 to +150	°C			
Soldering temperature (1)		T _{sld}	260	°C			

Notes

⁽¹⁾ Wave soldering three cycles are allowed. Also refer to "Assembly Instructions" (www.vishay.com/doc?80054).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	I _F = 20 mA	V _F	-	1.1	1.4	V	
Junction capacitance	$V_R = 0 V, f = 1 MHz$	C _j	-	50	-	pF	
OUTPUT							
Collector emitter voltage	I _C = 1 mA	V _{CEO}	32	-	-	V	
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7	-	-	V	
Collector ermitter leakage current	V _{CE} = 10 V, IF = 0 A	I _{CEO}	-	15	100	nA	
COUPLER							
Collector emitter saturation voltage	$I_F = 20 \text{ mA}, I_C = 5 \text{ mA}$	V _{CEsat}	-	-	1	V	
Cut-off frequency	V_{CE} = 5 V, I_F = 10 mA, R_L = 100 Ω	f _c	-	10	-	kHz	
Coupling capacitance	f = 1 MHz	C _k	-	0.3	-	pF	

Note

Minimum and maximum values are tested requierements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
I _C /I _F	$V_{CE} = 2 \text{ V}, I_F = 1 \text{ mA}$	CTR	600	800	-	%	

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

www.vishay.com

Vishay Semiconductors

SAFETY AND INSULATION RATED PARAMETERS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V _{pd}	2	-	-	kV	
Partial discharge test voltage -	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$	V_{IOTM}	8	-	-	kV	
lot test (sample test)	(see figure 2)	V_{pd}	1.68	-	-	kV	
Insulation resistance	V _{IO} = 500 V	R _{IO}	10 ¹²	-	-	Ω	
	$V_{IO} = 500 \text{ V}, T_{amb} = 100 \text{ °C}$	R _{IO}	10 ¹¹	-	-	Ω	
	V _{IO} = 500 V, T _{amb} = 150 °C (construction test only)	R _{IO}	10 ⁹	-	-	Ω	
Forward current		I _{si}	130	-	-	mA	
Power dissipation		P _{so}	265	-	-	mW	
Rated impulse voltage		V _{IOTM}	8	-	-	kV	
Safety temperature		T _{si}	150	-	-	°C	
Clearance distance			8.0	-	-	mm	
Creepage distance			8.0	-	-	mm	
Insulation distance (internal)			0.40	-	-	mm	

Note

According to DIN EN 60747-5-2 (VDE 0884) (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety
ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

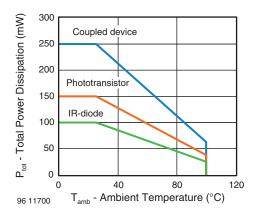


Fig. 1 - Derating Diagram

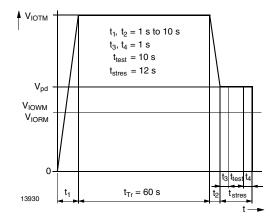
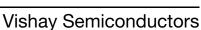


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-2 (VDE 0884); IEC 60747-5-5

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Rise time	$V_{CE} = 2 \text{ V}, I_{C} = 10 \text{ mA}, R_{L} = 100 \Omega \text{ (see Fig. 3)}$	t _r	-	300	-	μs
Turn-off time	$V_{CE} = 2 \text{ V}, I_{C} = 10 \text{ mA}, R_{L} = 100 \Omega \text{ (see Fig. 3)}$	t _{off}	-	250	-	μs





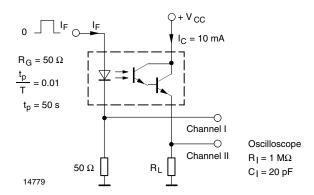


Fig. 3 - Test Circuit, Non-Saturated Operation

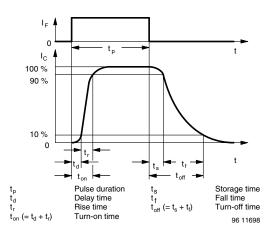


Fig. 4 - Switching Times

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

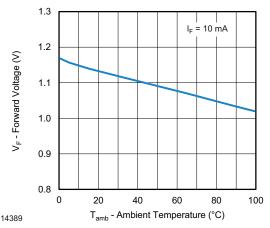


Fig. 5 - Forward Voltage vs. Ambient Temperature

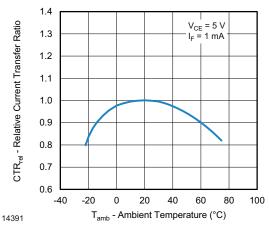


Fig. 7 - Relative Current Transfer Ratio vs. Ambient Temperature

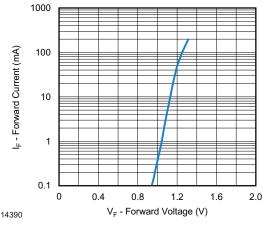


Fig. 6 - Forward Current vs. Forward Voltage

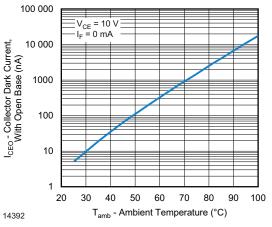


Fig. 8 - Collector Dark Current vs. Ambient Temperature



Vishay Semiconductors

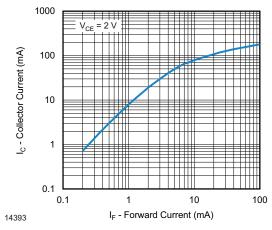


Fig. 9 - Collector Current vs. Forward Current

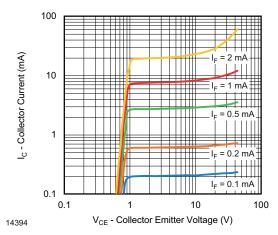
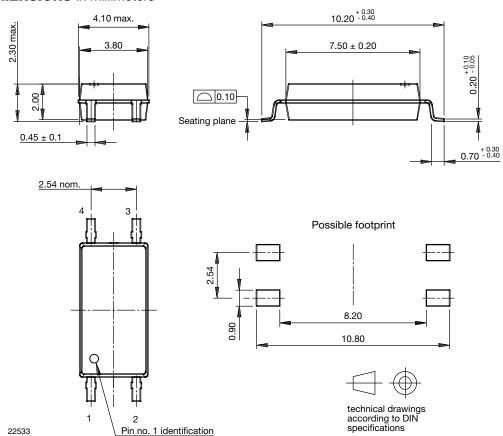


Fig. 10 - Collector Current vs. Collector Emitter Voltage

PACKAGE DIMENSIONS in millimeters







Vishay Semiconductors

TCLD1000 V XXXX 68

Note

• XXXX = LMC (lot marking code)



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.